

500V breakdown voltage Full bridge driver IC SMA2417M (Negative drive system)

■ Features

- 500V breakdown voltage negative power supply drive system
- Encapsulate IGBT (4pieces) and a control MIC
- Sanken original ZIP package
- Suitable for inverter element for HID ballast unit

■ Absolute maximum ratings

No.	Item	Symbol	Unit	Ratings	Conditions
1	Power Source Voltage	VM	V	500	Between Power GND and - HV
2	Input Voltage	VIN	V	15	
3	Operating Voltage	Vcc	V	15	
4	Output Voltage	VOUT	V	500	
5	Output Current	IOUT(DC)	A	7	Ta=25°C
6	Total Power Dissipation	PD	W	4 *1 20	Ta=25°C Tc=25°C
7	Storage Temperature	Tstg	°C	-40 ~ +150	
8	Junction Temperature	Tj	°C	-40 ~ +150	

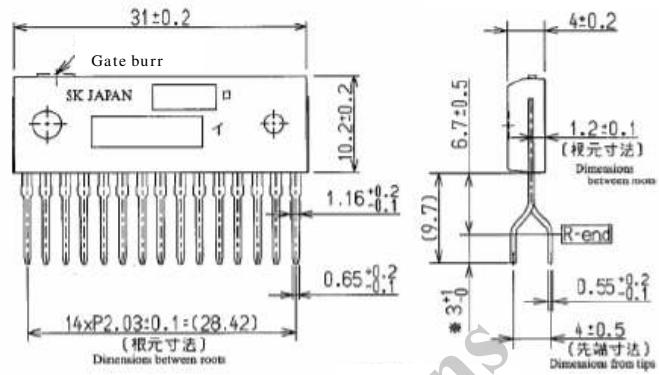
■ Electrical characteristics

No.	Item	Symbol	Unit	Value			Conditions
				Min.	Typ.	Max.	
1	IGBT Output Breakdown Voltage	BVOUT	V	* 500			IOUT=100μ A, Tj=40 ~ 150°C
				570			IOUT=100μ A, Tj=25°C
2	IGBT Output Leakage Current	IOUT(off)	μ A			100	VOUT=500V
3	IGBT Output On-State Voltage	VOUT(on)	V	1.0	1.2	IOUT=0.4A, VIN(or VGL)=10V	
				1.3	1.8	IOUT=2.0A, VIN(or GL)=10V	
4	Quiescent Circuit Current	Icc1	mA		3.0	Vcc=10V, VM=VIN=0V, Ta=25°C	
					4.5	Vcc=10 ~ 15V, VM=VIN=0V, Ta=40 ~ 125°C	
		Icc2	mA		4.0	Vcc=10V, VM=400V, VIN=0V, Ta=25°C	
					7.0	Vcc=9 ~ 15V, VM=400V, VIN=0V, Ta=40 ~ 125°C	
5	Operating Circuit Current	Icc3	mA	4.0	Vcc=10V, VM=400V, VIN1(or VIN2)=10V, Ta=25°C		
6	Input Threshold Voltage	VIH	V	0.8 · Vcc	7.0	Vcc=10V, VM=400V, VIN1(or VIN2)=10V, Ta=125°C	
7	Lowside IGBT Gate Drive Voltage	VGL	V	0.8 · Vcc	20	Vcc=9 ~ 15V	
8	Delay time	High side	td(on) td(off)	0.3	1.2	2.0	VM=85V, Io=0.41A Vcc=9 ~ 15V Vg=10V(Out Stage=ON) Vg=0V(Out Stage=OFF)
				0.5	1.5	2.5	
		Low side	td(on) td(off)	0.3	1.2	2.0	
				0.5	1.5	2.5	
			Δtd		1.0	*3	Δtd=H/S td(off) - L/S td(on) or L/S td(off) - H/S td(on)
9	Low voltage protection operation start voltage	VUVLOH	V	5.7	6.2	6.7	
		VUVLOL	V	5.3	6.0	6.6	
10	Low voltage protection operation start voltage Hysteresis width	Δ UVLO	V	0.1	0.2	0.4	Δ UVLO=VUVLOH-VUVLOL
11	Operating Voltage	VCC	V	9		15	Ta=-40 ~ +105°C

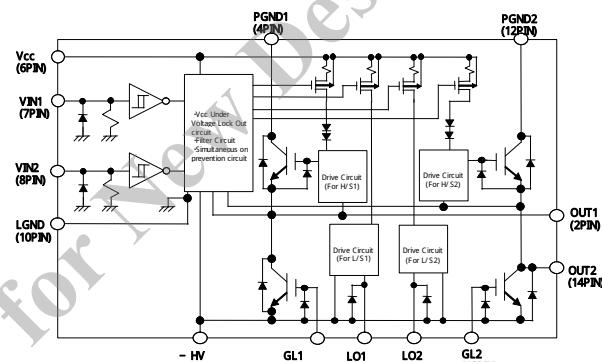
Recommended operation

No.	Item	Symbol	Unit	Value			Conditions
				Min.	Typ.	Max.	
1	Stability operation dV/dt	dV/dt	V/μ s		2		Ta=25°C, Vcc=10V, VM=400V
2	Recommended Dead time	td	μ s	1.0			Ta=-40 ~ +150°C

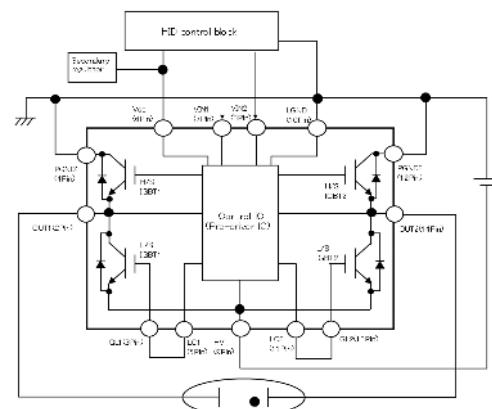
■ Package



■ Circuit block diagram



■ Typical connection diagram



■ Timing chart

